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## **VN2410L**

## **Small Signal MOSFET**

240 V, 200 mA, N-Channel TO-92

#### **Features**

• Pb-Free Packages are Available\*

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Drain – Source Voltage	V <sub>DSS</sub>	240	Vdc
Drain – Gate Voltage	$V_{DGR}$	240	Vdc
Gate – Source Voltage – Continuous – Non–repetitive (t <sub>p</sub> ≤ 50 μs)	V <sub>GS</sub> V <sub>GSM</sub>	± 20 ± 40	Vdc Vpk
Continuous Drain Current	I <sub>D</sub>	200	mAdc
Pulsed Drain Current	I <sub>DM</sub>	500	mAdc
Power Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	350 2.8	mW mW/°C
Operating and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to 150	°C

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	312.5	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/16 inch from case for 10 seconds	T <sub>L</sub>	300	ů

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

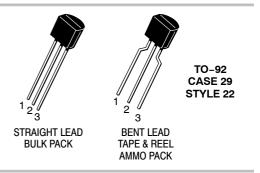


## ON Semiconductor®

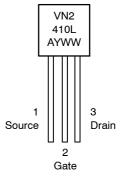
http://onsemi.com

**200 mA, 240 V**  $R_{DS(on)} = 10 \Omega$ 

# N-Channel D D



# MARKING DIAGRAM & PIN ASSIGNMENT



A = Assembly Location

Y = Year

WW = Work Week

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## VN2410L

## **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

	Symbol	Min	Max	Unit	
STATIC CHARACTERISTICS				-	•
Drain – Source Breakdown Voltag $(V_{GS} = 0, I_D = 100 \mu A)$	е	V <sub>(BR)DSS</sub>	240	_	Vdc
Zero Gate Voltage Drain Current $(V_{DS} = 120 \text{ Vdc}, V_{GS} = 0)$ $(V_{DS} = 120 \text{ Vdc}, V_{GS} = 0, T_A = 0)$	125°C)	I <sub>DSS</sub>	- -	10 500	μAdc
Gate- Body Leakage (V <sub>DS</sub> = 0, V <sub>GS</sub> = ±15 V)		I <sub>GSS</sub>	-	±100	nAdc
Gate Threshold Voltage (V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 1.0 mA)	V <sub>GS(th)</sub>	0.8	2.0	Vdc	
On-State Drain Current (Note 1) ( $V_{GS} = 10 \text{ V}, V_{DS} \ge 2.0 \text{ V}_{DS(on)}$	I <sub>D(on)</sub>	1.0	_	Adc	
Drain–Source On Resistance (No $(V_{GS} = 2.5 \text{ V}, I_D = 0.1 \text{ A})$ $(V_{GS} = 10 \text{ V}, I_D = 0.5 \text{ A})$	te 1)	r <sub>DS(on)</sub>	- -	10 10	Ω
Forward Transconductance (Note (V <sub>DS</sub> = 10 V, I <sub>D</sub> = 0.5 A)	9 <sub>fs</sub>	300	-	mS	
DYNAMIC CHARACTERISTIC	DS .			-	•
Input Capacitance		C <sub>iss</sub>	-	125	pF
Output Capacitance	$(V_{DS} = 25 \text{ Vdc}, V_{GS} = 0, \\ f = 1.0 \text{ MHz})$	c, V <sub>GS</sub> = 0,	-	50	pF
Reverse Transfer Capacitance	<u>-</u> ,	C <sub>rss</sub>	-	20	pF
SWITCHING CHARACTERIST	TICS				
Turn-On Time		t <sub>(on)</sub>	-	8.0	ns
	(V <sub>DD</sub> = 60 Vdc, I <sub>D</sub> = 0.4 A,	t <sub>(r)</sub>	-	8.0	ns
Turn-Off Time	$R_L = 150 \Omega$ , $R_G = 25 \Omega$ )	t <sub>(off)</sub>	-	23	ns
		t <sub>(f)</sub>	-	34	ns

<sup>1.</sup> Pulse Test; Pulse Width  $< 300 \mu s$ , Duty Cycle  $\le 2.0\%$ .

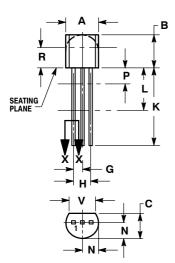
## **ORDERING INFORMATION**

Device	Package	Shipping
VN2410L	TO-92	1000 Units / Box
VN2410LG	TO-92 (Pb-Free)	1000 Units / Box
VN2410LZL1	TO-92	2000 Ammo Pack
VN2410LZL1G	TO-92 (Pb-Free)	2000 Ammo Pack

## VN2410L

## PACKAGE DIMENSIONS

TO-92 CASE 29-11 ISSUE AM



STRAIGHT LEAD **BULK PACK** 



**BENT LEAD** 

**TAPE & REEL** 

AMMO PACK

#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  CONTROLLING DIMENSION: INCH.
- CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED. LEAD DIMENSION IS UNCONTROLLED IN P AND
- BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	

#### STYLE 22:

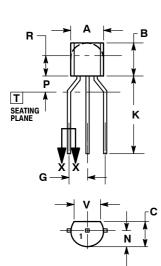
PIN 1. SOURCE GATE

3. DRAIN

## NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M. 1994.
- CONTROLLING DIMENSION: MILLIMETERS.
- 3
- CONTOUR OF PACKAGE BEYOND
  DIMENSION R IS UNCONTROLLED.
  LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM

	MILLIMETERS		
DIM	MIN	MAX	
Α	4.45	5.20	
В	4.32	5.33	
C	3.18	4.19	
D	0.40	0.54	
G	2.40	2.80	
7	0.39	0.50	
K	12.70		
N	2.04	2.66	
Р	1.50	4.00	
R	2.93		
V	3 43		





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